Substitution Effects on the Thermal Extrusion of Silylenes from 1,1-Diarylsilacyclopropenes

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Thermal extrusion of silylenes from 1,1-dimesitylsilacyclopropenes and 1,1-bis(2,6dimethoxyphenyl)silacyclopropene was studied. Heating 1,1-dimesityl-2-(trimethylsilyl)-3phenyl-1-silacyclopropene at 250 °C led to the clean formation of dimesitylsilylene, which was readily trapped by methyldiphenylsilane, giving the insertion product. The rate of the silylene extrusion was affected by the substituents at the ring silicon and carbon atoms. Thus, replacement of the phenyl group on the carbon by a trimethylsilyl group, as well as substitution of the silicon by 2,6-dimethoxyphenyl groups in place of mesityls, clearly facilitate the silvlene extrusion.

Introduction

Silicon-containing small-ring compounds are of importance in the field of organosilicon chemistry.¹ Of these, silacyclopropenes constitute one of the most strained classes of organosilacycles, and their chemical behavior has been extensively studied. Insertion reactions of unsaturated organic compounds into the silacyclopropene Si-C bond and head-to-tail dimerization of silacyclopropenes in the presence or absence of a transition-metal catalyst provide convenient methodologies leading to organosilacycles, such as siloles and disilacyclohexadienes.² They also undergo a variety of reactions, depending on the substituents on the ring. Sekiguchi et al. have reported the formation of 2,2dilithiotrisilane from the cleavage of the inner-ring Si-C bonds of tetrasilylsilacyclopropene by interaction with lithium.³ It has been reported by Kira et al. that facile silylene extrusion from 1,1-diamino-2,3-bis(trimethylsilyl)silacyclopropenes occurs exclusively under photochemical conditions,⁴ in contrast to the fact that photochemical isomerization to 1-silapropadienes has been often noted for silyl-, alkyl-, and aryl-substituted silacyclopropenes.⁶ Interesting isomerization leading to disilabenzvalene has been reported for bis(silacyclopropene) by Ando and co-workers.⁵

Recently, we have found that 1,1-dimesityl-3-phenyl-2-(trimethylsilyl)silacyclopropene (1a) may be an efficient silvlene precursor and heating 1a at 250 °C cleanly produces phenyl(trimethylsilyl)acetylene and dimesitylsilylene. Dimesitylsilylene thus produced can be readily trapped by methyldiphenylsilane, diphenylacetylene, and 1,4-bis(trimethylsilyl)butadiyne.⁷ This is in contrast to similar thermal reactions of 1-(trimethylsilyl)-1-arylsilacyclopropenes, which afford complex mixtures arising from isomerization of the silacyclopropenes.⁸ In this paper, we report the thermal reactions of 1,1-dimesityl- and 1,1-bis(2,6-dimethoxyphenyl)silacyclopropenes having trimethylsilyl or phenyl groups on the ring carbons. These reactions produced the corresponding silylenes cleanly, and the rate of silylene extrusion was considerably affected by the nature of the substituents on the ring silicon and carbon atoms. Crystal structures of the silacyclopropenes and reaction heats for the silylene extrusion were obtained from X-ray diffraction studies and molecular orbital (MO) calculations, respectively, to understand the substitution effects.

Results and Discussion

Synthesis of Silacyclopropenes. The starting silacyclopropenes were obtained as shown in Scheme 1. Thus, 2-(trimethylsilyl)silacyclopropenes (1a,6a,9 1b,6b and 2a) were readily prepared by the photochemical isomerization of ethynyldisilanes.¹⁰ The precursors of

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1a and **1b** were obtained by successive treatment of 1,1,1-trichlorotrimethyldisilane with 2 equiv of mesityllithium and 1 equiv of the corresponding ethynyllithium. Since the reaction of 1,1,1-trichlorotrimethyldisilane with 2 equiv of (2,6-dimethoxyphenyl)lithium gave only the monosubstitution product, it was necessary to start with 1,1,1-trifluorotrimethyldisilane for the preparation of the precursor of **2a**. 1,1-Dimesityl-2,3diphenylsilacyclopropene (**1c**) was obtained by the reaction of photochemically generated dimesitylsilylene with diphenylacetylene.¹¹ The present silacyclopropenes are stable in air and can be handled without special care.

Silylene Extrusion from 1,1-Dimesitylsilacyclopropenes 1a–c. When silacyclopropenes 1a,b were heated in a degassed sealed glass tube in the presence of an excess of methyldiphenylsilane as the silylene

Scheme 2



Table 1. Reactions of Silacyclopropenes in thePresence of Methyldiphenylsilane for 24 h

| compd | | product yield ^a /% | | | |
|-------|---------|-------------------------------|--------------------|-------------------------------|--|
| | temp/°C | Ph2MeSiAr2SiH | $R^1C \equiv CR^2$ | silacyclopropene ^b | |
| 1a | 250 | 90 | 90 | 5 | |
| | 220 | 16 | 16 | 75 | |
| | 190 | 0 | 0 | 100 | |
| 1b | 220 | 85 | 80 | 2 | |
| | 180 | 67 | 68 | 18 | |
| 1c | 250 | 0 | 0 | 100 | |
| 2a | 250 | 87 | 87 | 0 | |
| | 220 | 55 | 56 | 32 | |

 a Determined by ¹H NMR spectrum of the reaction mixture. b Silacyclopropene recovered.

trapping agent,¹² the trapped products were obtained, together with the corresponding acetylenes as shown in Scheme 2 and Table 1. The ¹H and ¹³C NMR spectra of the reaction mixtures indicated that silylene extrusion had occurred in excellent yields based on the consumed silacyclopropenes, although some unidentified signals in low intensity were always observed in the spectra. Thus, heating silacyclopropene 1a at 250 °C for 24 h resulted in a 90% yield of dimesityl-1-methyl-1,1diphenyldisilane (3) together with phenyl(trimethylsilyl)acetylene. However, **1a** did not react at 190 °C and the starting **1a** was recovered unchanged. Similarly, when diphenylsilacyclopropene 1c was heated at 250 °C in the presence of an excess of methyldiphenylsilane, no change was observed and the starting compound 1c was recovered quantitatively. In contrast to this, bis-(trimethylsilyl)silacyclopropene **1b** underwent silylene extrusion even at 180 °C to an extent, giving 3 in 67% yield, together with a 18% yield of 1b recovered. These results indicate the clear dependence of the rate of silvlene extrusion on the nature of the substituents attached to the ring carbons; i.e., the rate increased by replacing the phenyl group with a trimethylsilyl group, in the order 1c < 1a < 1b.

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Table 2. Selected Bond Distances (Å) and Angles (deg) for Compounds 1a-c and 2a with Their Esd's in Parentheses

| compd | C=C | Si-C(Ph) | Si-C(SiMe) | compd | C=C | Si-C(Ph) |
|-----------|----------|----------------------|------------|--------------|-----------------------------------|--------------------|
| 1a | 1.349(3) | 1.800(2) | 1.839(2) | 1c | 1.347(3) | 1.816(2), 1.818(2) |
| 1b | 1.363(7) | | 1.829(4) | 2a | 1.348(6) | 1.782(4) |
| compd | Ph-C=C | Ph-C-Si | C=C(Ph)-Si | MeSi-C=C | MeSi-C-Si | C=C(SiMe)-Si |
| 1a | 137.1(2) | 152.8(2) | 69.8(1) | 143.3(2) | 149.6(1) | 66.7(1) |
| 1b 1- | 107 E(9) | 1 = 1 = 1 = (9) | 138.0(1) | 153.2(2) | 68.1(1) | |
| Ic | 137.5(2) | 154.1(2) 154.0(2) | 68 2(1) | | | |
| 2a | 136.6(4) | 153.5(4) | 69.7(3) | 146.9(4) | 146.6(3) | 66.4(3) |
| | | | | | | |
| | | | | CS | | C11 |
| Cl | 13 | Y _D ≫C13 | 3* | C6 0 | | C12 |
| | C11 | | | | 🕀 C4 | C10 |
| | (Hara | C11* | | Д | 11 | A L |
| C12 | S12 | Si2 | * | C7 🖉 | | C13 |
| | | | | | C3 | |
| \oslash | | | | O | C1 $C2/$ | C9 C14 |
| | - | $\neg p$ | C12* | Co | | × C14 |
| | | | | | \mathbb{N} | |
| | | M Dre | | | $\langle \langle \rangle \rangle$ | C32 |
| | C8* | Sil Sil | | | | <u>A</u> |
| | | (An | | C21 | Si1 | |
| | C3* | | | Ø. | | Т С29 |
| | | <u>⊅</u> Ø/C4 | | | C16 C15 C24 | × C28 |
| | C7 | | | | | 0.000 |
| C10 | | C7* | C10* | C30 | C25 C27 | ← (C23 |
| | C6 | (prov | 010 | 0.00 0 | C17 | C20 |
| | C9 | Det C6* | | | |) |
| | C | 5* | | | C18 C31 C1 | 9 |
| | | A | | | Ð | |
| | | ₩C9* | | | C22 | |

Figure 1. ORTEP view of compound **1b**. Protons are omitted for clarity. Thermal ellipsoids are drawn at 50% probability.

Compounds 1b and 1c crystallized from ethanol, and the structures were determined by X-ray diffraction studies, as shown in Figures 1 and 2. Selected bond distances and angles are given in Table 2, together with those of 1a, reported previously. As can be seen in Table 2, the inner-ring Si-C(SiMe) bond is considerably longer than the Si-C(Ph) bond in the structure of 1a. Furthermore, the C=C(SiMe)-Si angle is smaller than the C=C(Ph)-Si angle, while the C=C-SiMe angle is larger than the C=C-Ph angle. These are indicative of higher p character of the Si-C(SiMe) bond, as compared with the Si-C(Ph) bond. A similar tendency is also observed when the structures of **1b** and **1c** are compared, although it is less evident than that in **1a**. This may be due to the steric repulsion of the relatively large trimethylsilyl group as compared with the phenyl group. Electron-donating properties of the trimethylsilyl group may be also responsible for the longer Si-C(SiMe) bonds, by elevating the σ -orbital level. The inner-ring C=C bonds are elongated from the standard values,¹³ in the order 1c < 1a < 1b, agreeing with the rate of silvlene extrusion. It should be noted that the alkene unit in 1b is slightly twisted, as indicated by the torsion

Figure 2. ORTEP view of compound **1c**. Protons are omitted for clarity. Thermal ellipsoids are drawn at 50% probability.

angle for Me₃Si–C=C–SiMe₃ (15.5(9)°), while that of Ph–C=C–Ph in **1c** is only 5.9(5)°. The C=C bond length of **1b** (1.363 (7) Å) is extremely long and close to the values previously reported for twisted C=C bonds in tetrasilylethene (1.367–1.370 Å, torsion angle 22.6– 52.7°).¹⁴

To know more about the substitution effects, we carried out molecular orbital (MO) calculations for silylene extrusion from silacyclopropenes 1a-c at the level of B3LYP/6-31G(d,p).¹⁵ For these calculations, the silylene was assumed to have the singlet ground state.¹²

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Figure 3. ORTEP view of compound 2a. Protons are omitted for clarity. Thermal ellipsoids are drawn at 50% probability.

The optimized geometries of silacyclopropenes closely resemble those of the crystal structures, indicating the high reliability of the results of the MO calculations. The reactions were found to be highly endothermic, and the absolute values of the reaction heats decrease in the order 1c (43.3 kcal/mol) > 1a (39.4 kcal/mol) > 1b (33.1 kcal/mol), in good agreement with the experimental results. Attempts to find out the transition states (TSs) of the reactions were unsuccessful, probably due to the rather flat energy surface around the TSs. However, the highly endothermic profiles of the reactions seem to indicate that the TSs are highly product-like and would permit us to estimate the relative order of the activation energies of the reactions by comparing the reaction heats.

Silylene Extrusion from 1,1-Bis(2,6-dimethoxyphenyl)silacyclopropene (2a). Introduction of the 2,6-dimethoxyphenyl groups in place of the mesityl groups on the ring silicon atom markedly accelerated the rate of thermolysis. Thus, heating 2a at 220 °C led to a higher yield of trapped product, bis(2,6-dimethoxyphenyl)-1-methyl-1,1-diphenyldisilane (4), as compared with that from 1a at the same temperature (Table 1).

Acceleration of the reaction by the dimethoxyphenyl group may be understood in terms of the coordination of the oxygen atoms of the dimethoxyphenyl groups to the silacyclopropene ring silicon through an $n-\sigma^*$ type interaction, which would destabilize the ring Si-C bonds. However, the ²⁹Si NMR spectrum of **2a** showed the signal of the ring silicon at -122.2 ppm, at slightly higher field than that of 1a (-117.7 ppm), indicating that the coordination of the oxygen to the ring silicon is weak. Furthermore, the structural parameters of 2a determined by an X-ray diffraction study indicated inner-ring Si-C bond distances rather shorter than those in 1a (Table 1 and Figure 3), although the intramolecular contacts between the ring silicon and the oxygen atoms range from 3.08 to 2,80 Å, shorter than the sum of van der Waals radii (3.62 Å). We therefore assume that extracoodination of the oxygen atoms to



the silvlene center by n-p interaction¹² takes place in bis(2,6-dimethoxyphenyl)silylene to stabilize it, being primarily responsible for the accelerated silylene extrusion. Indeed, the MO calculations at the B3LYP/6-31G-(d,p) level led to a heat of formation of bis(2-methoxy-4,6-dimethylphenyl)silylene smaller by 6.9 kcal/mol than that obtained for bis(4-methoxy-2,6-dimethylphenyl)silylene, clearly indicating the stabilizing effect of the *o*-methoxy group on the silylene.¹⁵

Interestingly, when 2a was heated at 250 °C for 24 h with continuous removal of the resulting phenyl(trimethylsilyl)acetylene from the reaction mixture, 1,1,2,2tetrakis(2,6-dimethoxyphenyl)-4-phenyl-3-(trimethylsilyl)-1,2-disilacyclobut-3-ene (5) was produced in 28% yield, together with a 53% yield of the starting 2a recovered. Since simple heating of 2a without removing the acetylene at the same temperature resulted in the quantitative recovery of 2a, the silvlene would not react with 2a, probably due to the steric requirements. The formation of 5, therefore, may be better explained by assuming a disilene intermediate formed from dimerization of bis(2,6-dimethoxyphenyl)silylene (Scheme 3), rather than by insertion of the silvlene into an Si-C bond of 2a, although we have no evidence to confirm the formation of the disilene.

In conclusion, we demonstrated that the silylene extrusion from silacyclopropenes under the thermal conditions was considerably influenced by the nature of substituents on both the ring silicon and carbon atoms. We also attempted to understand the substitution effects by the comparison of structural parameters of the silacyclopropenes and MO calculations. However, the origin of the effects has not yet been unambiguously explained and further studies to understand it seem to be necessary.

Experimental Section

General Considerations. THF and ether were dried over sodium-potassium alloy and distilled just before use. Hexane and benzene were distilled from lithium aluminum hydride and stored over activated molecular sieves 4A before use. Silacyclopropenes 1a^{6a,9} and 1b,^{6b} 2,2-dimesitylhexamethyltrisilane,¹⁶ and 1,1,1-trifluorotrimethyldisilane¹⁷ were obtained as reported in the literature.

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Preparation of 1,1-Dimesityl-2,3-diphenyl-1-silacyclopropene (1c). A mixture of 0.824 g (2.00 mmol) of 2,2dimesitylhexamethyltrisilane and 1.78 g (10.0 mmol) of diphenylacetylene in 100 mL of hexane was irradiated for 1 h internally with a 6 W low-pressure mercury lamp bearing a Vycor filter. The solvent was evaporated, and the residue was chromatographed on a silica gel column with hexane as an eluent. The resulting crude solids were recrystallized from ethanol to give 0.49 g (55% yield) of **1c**: MS *m*/*z* 444 (M⁺); ¹H NMR (δ in CDCl₃) 2.24 (s, 6H), 2.42 (s, 12H), 6.81 (s, 4H), 7.26–7.61 (m, 10H); ¹³C NMR (δ in CDCl₃) 21.2, 24.0 (Me), 127.6, 128.2, 128.4, 128.7, 131.2, 134.9, 139.2, 144.1 (aromatic C), 152.4 (olefin C); ²⁹Si NMR (δ in CDCl₃) –111.0. Anal. Calcd for C₃₂H₃₂Si: C, 86.43; H, 7.25. Found: C, 86.13; H, 7.30.

Preparation of 1,1-Bis(2,6-dimethoxyphenyl)-1-(phenylethynyl)trimethyldisilane. In a 100 mL two-necked flask was placed 1.4 g (9.3 mmol) of 1,1,1-trifluorotrimethyldisilane in 10 mL of ether. To this was added a solution of (2,6dimethoxyphenyl)lithium prepared from treating 2.60 g (18.6 mmol) of *m*-dimethoxybenzene with 11.6 mL of a butyllithium/ hexane solution (1.6 M) in 15 mL of ether containing 0.05 mL of TMEDA at 0 °C.18 The mixture was stirred for 1 h at room temperature. To the mixture was then added a solution of (phenylethynyl)lithium prepared from 0.9 g (8.8 mmol) of phenylacetylene and 5.5 mL of a butyllithium/hexane solution (1.6 M) in 13 mL of hexane/THF (3/1). The resulting mixture was stirred for 1 h at room temperature and hydrolyzed with dilute hydrochloric acid. The organic layer was separated, and the aqueous layer was extracted with ether. The organic layer and the extracts were combined and dried over anhydrous magnesium sulfate. The solvent was evaporated, and the residue was chromatographed on a silica gel column with hexane/ethyl acetate (4/1) as an eluent, and the resulting crude solids were recrystallized from hexane to give 2.3 g (52% yield) of the title compound: MS m/z 476 (M⁺); ¹H NMR (δ in C₆D₆) 0.53 (s, 9H), 3.38 (s, 12H), 6.35 (d, 4H, J = 8.0 Hz, m-(MeO)₂C₆H₃), 6.97-7.05 (m, 3H, m-Ph and p-Ph), 7.18 (t, 2H, J = 8.0 Hz, p-(MeO)₂C₆H₃), 7.57 (dd, 2H, J = 7.2 Hz, J =2.0 Hz, o-Ph); ${}^{13}C$ NMR (δ in C₆D₆) -0.8, 55.2, 95.7, 104.2, 105.6, 113.2, 125.8, 127.6, 128.3, 131.0, 132.1, 165.3; IR $\nu_{C=C}$ 2152 cm⁻¹. Anal. Calcd for C₂₇H₃₂O₄Si₂: C, 68.03; H, 6.77. Found: C, 68.04; H, 6.66.

Preparation of 1,1-Bis(2,6-dimethoxyphenyl)-3-phenyl-2-(trimethylsilyl)-1-silacyclopropene (2a). A solution of 0.941 g (1.98 mmol) of 1,1-bis(2,6-dimethoxyphenyl)-1-(phenylethynyl)trimethyldisilane in a solvent mixture of 90 mL of hexane and 50 mL of benzene was irradiated for 2 h internally with a 6 W low-pressure mercury lamp bearing a Vycor filter. At this stage almost all of the starting disilane was photolyzed. The solvent was evaporated, and the residue was recrystallized from hexane and then from ethanol to give 0.263 g of 2a (28% yield): MS m/z 476 (M⁺); ¹H NMR (δ in C₆D₆) 0.51 (s, 9H), 3.45 (s, 12H), 6.29 (d, 4H, J = 8.3 Hz, m-(MeO)₂C₆H₃), 7.12 (t, 2H, J = 8.3 Hz, p-(MeO)₂C₆H₃), 7.25 (t, 1H, J = 7.5 Hz, p-Ph), 7.45 (br t, 2H, J = 7.5 Hz, m-Ph), 8.21 (d, 2H, J = 7.5 Hz, o-Ph); ¹³C NMR (δ in C₆D₆) 0.4 (MeSi), 55.1 (MeO), 103.7, 114.0, 130.5, 131.3, 137.3, 165.6 (aromatic C), 161.4, 177.5 (olefin C), two signals of aromatic carbons may overlap with those of the solvent C₆D₆; ²⁹Si NMR (δ in C₆D₆) -122.2 (ring Si), -13.2 (MeSi). Anal. Calcd for $C_{27}H_{32}O_4Si_2$: C, 68.03; H, 6.77. Found: C, 68.04; H, 6.71.

Thermolysis of Silacyclopropenes in the Presence of Methyldiphenylsilane. An illustrative procedure is as follows. In a degassed, sealed glass tube was placed 20 mg (0.050 mmol) of 1a and 50 mg (0.25 mmol) of dimethylphenylsilane, and the tube was heated at 250 °C for 24 h. The resulting mixture was dissolved in C_6D_6 and analyzed with respect to the ¹H NMR spectrum, using decane as an internal standard,

Table 3. Crystal Data, Experimental Conditions, and Summary of Structural Refinement Details for Silacyclopropenes

| | | - | | |
|--|---------------------------------|---|--|--|
| | 1b | 1c | 2a | |
| mol formula | C26H40Si3 | C ₃₂ H ₃₂ Si | C27H32O4Si2 | |
| mol wt | 436.86 | 444.69 | 476.72 | |
| space group | C2/c (No. 15) | <i>P</i> 2 ₁ / <i>c</i> (No. 14) | <i>P</i> 4 _{<i>n</i>} / <i>n</i> (No. 86) | |
| cell dimens | | | | |
| <i>a</i> , Å | 20.9888(3) | 15.7858(6) | 21.2906(5) | |
| b, Å | 10.0371(4) | 10.0472(3) | | |
| <i>c</i> , Å | 16.5044(3) | 17.5286(4) | 11.7996(3) | |
| β , deg | 127.007(2) | 114.196(2) | | |
| V, Å ³ | 2776.5(1) | 2535.9(1) | 5348.6(2) | |
| Z | 4 | 4 | 8 | |
| D_{calcd} , Mg/m ³ | 1.045 | 1.165 | 1.184 | |
| F ₀₀₀ | 952.00 | 952.00 | 2032.00 | |
| cryst size, mm ³ | $0.5\times0.5\times0.1$ | $0.6\times0.3\times0.2$ | $0.4\times0.1\times0.1$ | |
| cryst color | colorless | colorless | colorless | |
| μ , cm ⁻¹ | 1.80 | 1.10 | 1.61 | |
| radiation | Μο Κα | | | |
| $2\theta \max$ | 55.0 | 54.9 | 55.0 | |
| no. of unique rflns | 3169 | 5782 | 6143 | |
| no. of obsd rflns $(I > 2 \sigma(I))$ | 2070 | 4949 | 2486 | |
| $(I \ge 30(I))$ ref/params | 15.7 | 16.6 | 8.34 | |
| corrections | Lorentz-polarization absorption | | | |
| abs range | 0.516 - 0.982 | 0.884 - 0.978 | 0.730-0.984 | |
| R | 0.095 | 0.095 | 0.079 | |
| $R_{ m w}{}^a$ | 0.162 | 0.228 | 0.088 | |
| | | | | |

^{*a*} The weighting scheme is $(\sigma(F_0)^2 + 0.0004|F_0|^2)^{-1}$.

as being 3 (90% yield), phenyl(trimethylsilyl)acetylene (90% yield), and the starting 1a (5% yield). Products were separated from the mixture by preparative TLC. The ¹H and ¹³C NMR spectra obtained for phenyl(trimethylsilyl)acetylene were identical with those of the authentic sample.¹⁹ Data for **3**: MS m/z485 (M⁺ – Me); ¹H NMR (δ in CDCl₃) 0.79 (s, 3H), 2.09 (s, 12H), 2.24 (s, 6H), 5.36 (s, 1H, SiH), 6.74 (s, 4H, Mes), 7.22-7.40 (m, 10H, Ph); ^{13}C NMR (δ in $C_6D_6)$ –3.2, 21.0, 24.0, 127.7, 128.4, 128.9, 129.5, 135.1, 137.1, 138.5, 144.7. Anal. Calcd for C31H36Si2: C, 80.11; H, 7.81. Found: C, 80.10; H, 7.74. Thermolysis of 1b,c and 2a was carried out as above. Data for 4: MS m/z 485 (M⁺ – Me); ¹H NMR (δ in C₆D₆) 0.85 (s, 3H), 3.13 (s, 12H), 5.99 (s, 1H, SiH), 6.28 (d, 4H, J = 8.3 Hz, m-(MeO)₂C₆H₃), 7.13-7.17, 7.68-7.71 (m, 12H, ring H); ¹³C NMR (δ in CDCl₃) -3.1, 54.8, 103.5, 111.3, 131.1, 135.3, 140.2, 165.3, two signals of phenyl meta and para carbons may overlap with those of the solvent C6D6. Anal. Calcd for C₂₉H₃₂O₄Si₂: C, 69.56; H, 6.44. Found: C, 69.56; H, 6.37.

Formation of 5. In one end of a sealed, V-shaped glass tube was placed 0.590 g (1.24 mmol) of 2a, and the end was heated at 250 °C for 24 h while the other end was cooled by liquid nitrogen. Phenyl(trimethylsilyl)acetylene was collected at the cooled end as the colorless liquid. The products at both ends were combined and analyzed by ¹H NMR, using decane as an internal standard, as being phenyl(trimethylsilyl)acetylene (0.24 mmol, 40%) and 5 (0.16 mmol, 55%), together with a 53% yield of 2a recovered. The mixture was subjected to preparative TLC with hexane/ethyl acetate (5/1) as an eluent, and the resulting crude solids were recrystallized from hexane to give 34 mg (7%) of 5: MS m/z 778 (M⁺); ¹H NMR (δ in C₆D₆) 0.19 (s, 9H), 3.06 (s, 12H), 3.23 (s, 12H), 6.21 (d, 4H, J = 8.3 Hz), 6.29 (d, 4H, J = 8.3 Hz), 7.10 (t, 2H, J = 8.1 Hz), 7.16 (t, 2H, J = 8.1 Hz), 7.31 (t, 2H, J = 7.6 Hz), 7.43 (dd, 2H, J = 8.3 Hz, 1.5 Hz), the phenyl para proton signal may overlap with that of the solvent C₆D₅H; ¹H NMR (δ in acetone- d_6) -0.29 (s, 9H), 3.17 (s, 12H), 3.33 (s, 12H), 6.25 (d, 4H, J = 8.1 Hz), 6.36 (d, 4H, J = 8.1 Hz), 7.00–7.21 (m, 9H); ¹³C NMR (δ in acetoned₆) 1.65, 54.6, 55.1, 103.0, 103.5, 116.1, 116.8, 124.5, 126.9, 128.0, 130.4, 130.7, 150.9, 165.3, 165.7, 174.2, 185.2; ²⁹Si NMR (δ in CDCl₃) -18.7, -11.1, -9.3. Anal. Calcd for C₄₃H₅₀O₈Si₃: C, 66.29; H, 6.47. Found: C, 66.35; H, 6.46.

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X-ray Crystallographic Analysis of Silacyclopropenes. Crystal data, experimental conditions, and a summary of structural refinement details for **1b**,**c** and **2a** are presented in Table 3. Data were collected on a Rigaku RAXIS imaging plate system at 100 K. The structure was solved by SIR92 direct methods.²⁰ The non-hydrogen atoms were refined anisotropically. Neutral atom scattering factors were taken from Cromer and Waber.²¹ Anomalous dispersion effects were included in F_c ;²² the values for $\Delta f'$ and $\Delta f''$ were those of Creagh and McAuley.²³ The values for the mass attenuation coefficients are those of Creagh and Hubbel.²⁴ All calculations were performed using the teXsan²⁵ crystallographic software package of Molecular Structure Corp. No decay correction was applied.

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Supporting Information Available: Tables of positional and anisotropic displacement parameters and bond distances and angles for compounds **1b,c** and **2a**. This material is available free of charge via the Internet at http://pubs.acs.org.

OM020996H

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